

# isc N-Channel MOSFET Transistor

# **IRF1503S**

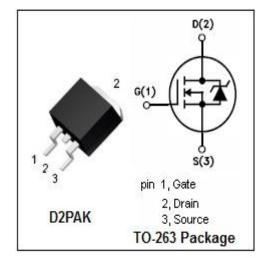
### • FEATURES

- With TO-263( D2PAK ) packaging
- · High speed switching
- · Low gate input resistance
- · Standard level gate drive
- · Easy to use
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation



### APPLICATIONS

- Power supply
- · Switching applications

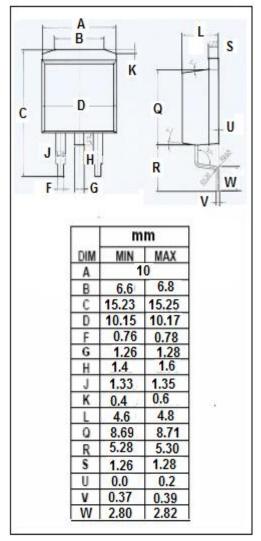


## • ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT	
V <sub>DSS</sub>	Drain-Source Voltage	30	V	
V <sub>GSS</sub>	Gate-Source Voltage	±20	V	
I <sub>D</sub>	Drain Current-Continuous;Tc=25℃ Tc=100℃	190 140	А	
$I_{DM}$	Drain Current-Single Pulsed	960	А	
P <sub>D</sub>	Total Dissipation	200	W	
Tj	Operating Junction Temperature	150	$^{\circ}\mathbb{C}$	
T <sub>stg</sub>	Storage Temperature	-55~150	$^{\circ}$	

## • THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
Rth(ch-c)	Channel-to-case thermal resistance	0.75	°C/W
Rth(ch-a)	h(ch-a) Channel-to-ambient thermal resistance		°C/W





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#### **ELECTRICAL CHARACTERISTICS**

T<sub>c</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; I <sub>D</sub> = 0.25mA	30			V
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> =V <sub>GS</sub> ; I <sub>D</sub> =0.25mA	2.0		4.0	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> =140A		2.6	3.3	mΩ
I <sub>GSS</sub>	Gate-Source Leakage Current	V <sub>GS</sub> =±20V;V <sub>DS</sub> = 0V			±0.2	μА
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> = 30V; V <sub>GS</sub> = 0V;Tc=25°C V <sub>DS</sub> = 24V; V <sub>GS</sub> = 0V; Tc=125°C			20 250	μА
V <sub>SDF</sub>	Diode forward voltage	I <sub>SD</sub> =140A, V <sub>GS</sub> = 0 V			1.3	V

## **NOTICE:**

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